

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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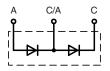




Power Schottky Rectifier dual diode

V _{RRM}	= 100 V
V_{F}	= 0.63 V

V _{RSM}	V _{RRM}	Туре
V 100	100	DSSS 30-01AR





= 2x30 A

C = Cathode, A = Anode

Conditions	Maximum Ratings	
	70	A
$T_{\rm C} = 155^{\circ}$ C; rectangular, d = 0.5	30	Α
$T_C = 155$ °C; rectangular, d = 0.5; per device	60	Α
$T_{VJ} = 45^{\circ}C; t_p = 10 \text{ ms (50 Hz), sine}$	600	Α
$I_{AS} = 15 \text{ A}$; L = 100 μH ; $T_{VJ} = 25^{\circ}\text{C}$; non repetitive	11.3	mJ
$V_A = 1.5 \bullet V_{RRM}$ typ.; f=10 kHz; repetitive	1.5	Α
	5000	V/µs
	-55+175	°C
	175	°C
	-55+150	°C
T _C = 25°C	190	W
mounting force with clip	20120	N
50/60 Hz, RMS; t = 1 s	3000	٧~
typical	6	g
	T_{C} = 155°C; rectangular, d = 0.5 T_{C} = 155°C; rectangular, d = 0.5; per device T_{VJ} = 45°C; t_{p} = 10 ms (50 Hz), sine I_{AS} = 15 A; L = 100 μ H; T_{VJ} = 25°C; non repetitive V_{A} =1.5 • V_{RRM} typ.; f=10 kHz; repetitive T_{C} = 25°C mounting force with clip 50/60 Hz, RMS; t = 1 s	$T_{\text{C}} = 155^{\circ}\text{C}; \text{ rectangular, d} = 0.5 \\ T_{\text{C}} = 155^{\circ}\text{C}; \text{ rectangular, d} = 0.5; \text{ per device} \\ 60 \\ T_{\text{VJ}} = 45^{\circ}\text{C}; \text{ t}_{\text{p}} = 10 \text{ ms (50 Hz), sine} \\ 600 \\ I_{\text{AS}} = 15 \text{ A; L} = 100 \mu\text{H; T}_{\text{VJ}} = 25^{\circ}\text{C; non repetitive} \\ 11.3 \\ V_{\text{A}} = 1.5 \bullet V_{\text{RRM}} \text{ typ.; f=10 kHz; repetitive} \\ 1.5 \\ 5000 \\ -55+175 \\ 175 \\ -55+150 \\ T_{\text{C}} = 25^{\circ}\text{C} \\ 190 \\ \text{mounting force with clip} \\ 20120 \\ 50/60 \text{ Hz, RMS; t=1 s} \\ 3000 \\ \end{cases}$

Symbol	Conditions	Chara	Characteristic Values		
		typ.	max.		
I _R ①	$V_R = V_{RRM}$; $T_{VJ} = 25^{\circ}C$ $V_R = V_{RRM}$; $T_{VJ} = 125^{\circ}C$		2 20	mA mA	
V _F	$I_F = 30 \text{ A};$ $T_{VJ} = 125^{\circ}\text{C}$ $I_F = 30 \text{ A};$ $T_{VJ} = 25^{\circ}\text{C}$ $I_F = 60 \text{ A};$ $T_{VJ} = 125^{\circ}\text{C}$		0.63 0.79 0.78	V V V	
R _{thJC}		0.25	0.8	K/W K/W	

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0% Data according to IEC 60747 and per diode unless otherwise specified

Features

- · International standard package
- Very low V_F
- Extremely low switching losses
- Low I_{RM}-values
- Isolated and UL registered E153432

Applications

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Advantages

- · High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- · Low noise switching
- Low losses

Dimensions see Outlines.pdf



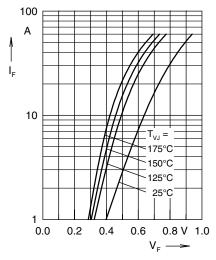
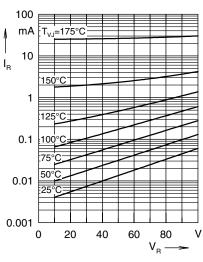


Fig. 1 Max. forward voltage drop characteristics



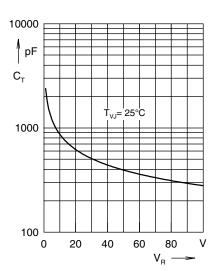


Fig. 3 Typ. junction capacitance C_T vs. reverse voltage V_B

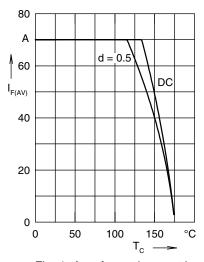


Fig. 4 Avg. forward current $I_{\text{F(AV)}}$ vs. case temperature T_{C}

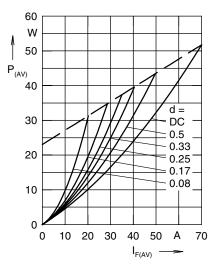


Fig. 5 Forward power loss characteristics

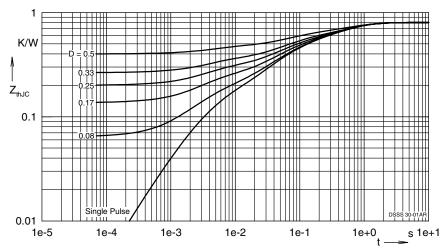


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode